

**2SA1434**

High h_{FE} , Low-Frequency General-Purpose Amp Applications

Applications

- Low frequency general-purpose amplifiers, drivers, muting circuits.

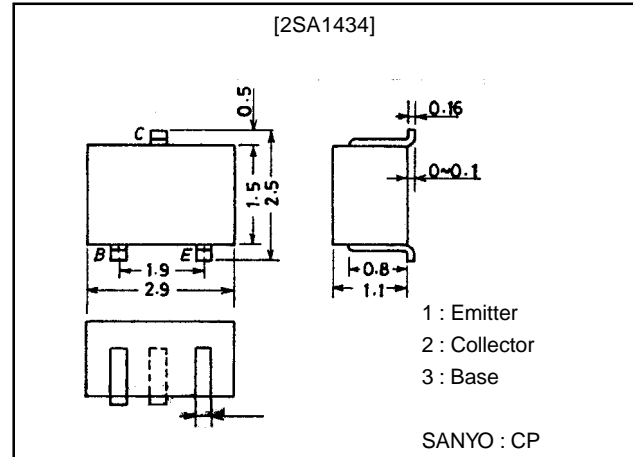
Features

- Very small-sized package permitting 2SA1434-used sets to be made smaller, slimer.
- Adoption of FBET process.
- High DC current gain ($h_{FE}=500$ to 1200).
- Low collector-to-emitter saturation voltage ($V_{CE(sat)} \leq 0.5V$).
- High V_{EBO} ($V_{EBO} \geq 15V$).

Package Dimensions

unit:mm

2018A



Specifications

Absolute Maximum Ratings at $T_a = 25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		-60	V
Collector-to-Emitter Voltage	V_{CEO}		-50	V
Emitter-to-Base Voltage	V_{EBO}		-15	V
Collector Current	I_C		-100	mA
Collector Current (Pulse)	I_{CP}		-200	mA
Collector Dissipation	P_C		200	mW
Junction Temperature	T_J		125	$^\circ C$
Storage Temperature	T_{stg}		-55 to +125	$^\circ C$

Electrical Characteristics at $T_a = 25^\circ C$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=-40V, I_E=0$			-0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=-10V, I_C=0$			-0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=-5V, I_C=-10mA$	500	800	1200	
Gain-Bandwidth Product	f_T	$V_{CE}=-10V, I_C=-10mA$		100		MHz
Output Capacitance	C_{ob}	$V_{CB}=-10V, f=1MHz$		4.8		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-50mA, I_B=-1mA$	-0.2		-0.5	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=-10\mu A, I_B=-1mA$		-0.8	-1.1	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=-10\mu A, I_E=0$	-60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=-1mA, R_{BE}=\infty$	-50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=-10\mu A, I_C=0$	-15			V

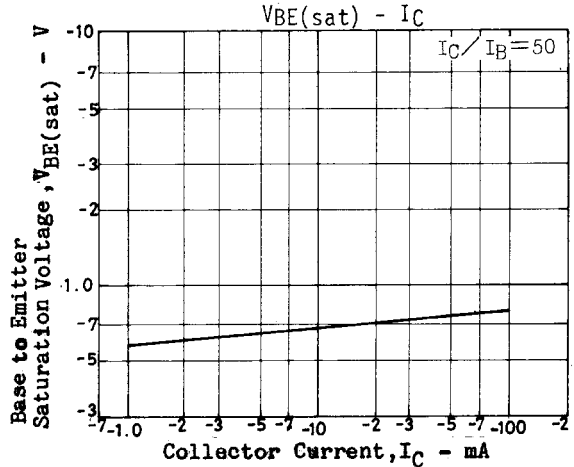
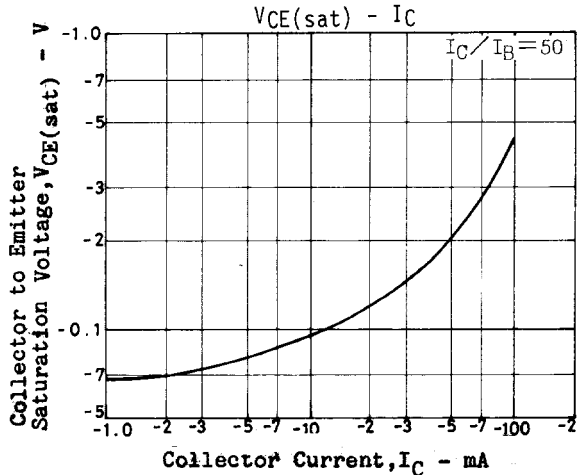
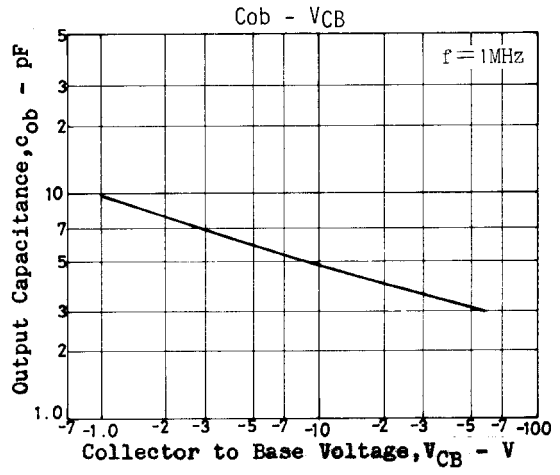
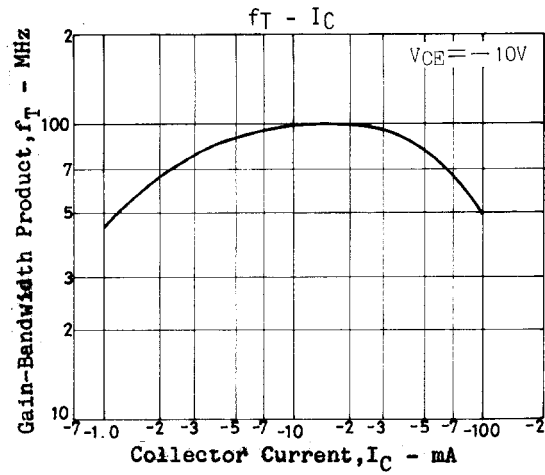
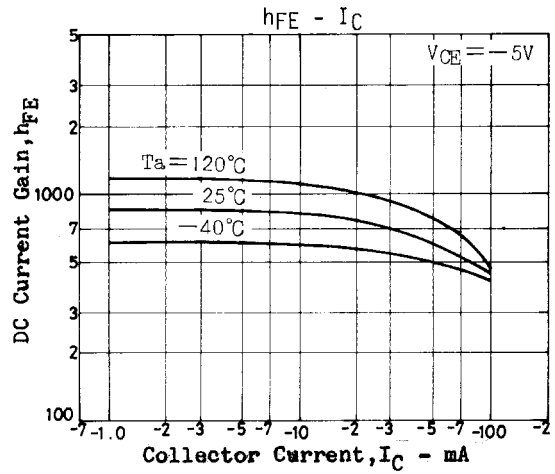
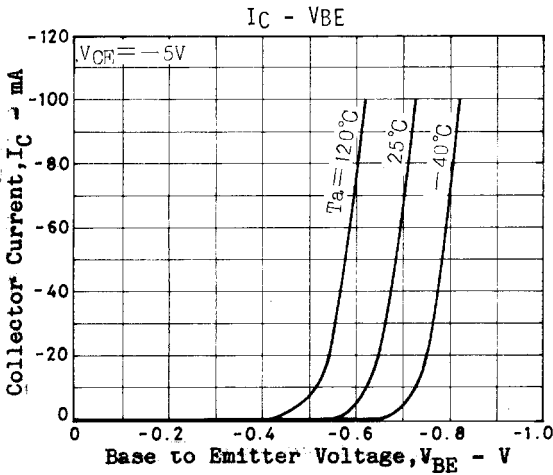
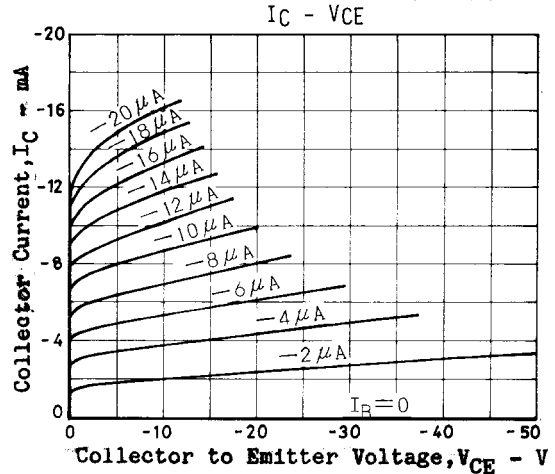
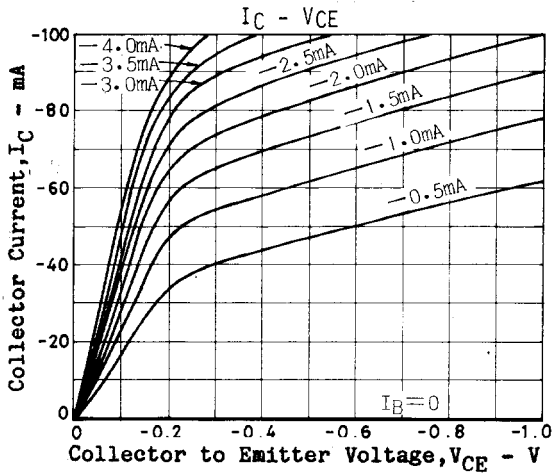
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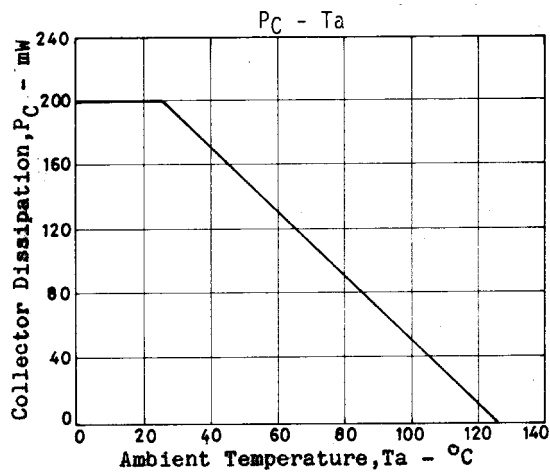
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